

HD74BC240A

Octal Buffers/Line Drivers With 3 State Outputs

HITACHI

ADE-205-006A (Z)
2nd. Edition
Mar. 1993

Description

The HD74BC240A provides high drivability and operation equal to or better than high speed bipolar standard logic IC by using Bi-CMOS process. The device features low power dissipation that is about 1/5 of high speed bipolar logic IC, when the frequency is 10 MHz. The device has eight inverter drivers with three state outputs in a 20 pin package. This device is a non inverting buffer and has two active low enables ($\overline{1G}$ and $\overline{2G}$). Each enable independently controls 4 buffers.

Features

- Input/Output are at high impedance state when power supply is off.
- Built in input pull up circuit can make input pins be open, when not used.
- TTL level input
- Wide operating temperature range
 $T_a = -40$ to $+85^\circ\text{C}$

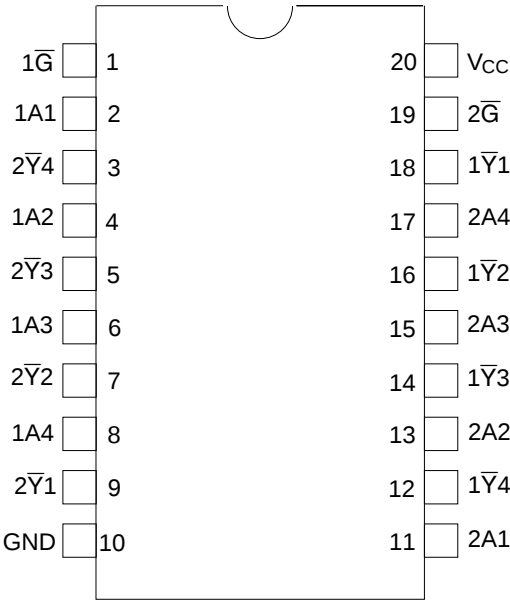
Function Table

Inputs

$\overline{G}$	A	Output $\overline{Y}$
H	X	Z
L	H	L
L	L	H

H : High level
L : Low level
X : Immaterial
Z : High impedance

Pin Arrangement



(Top view)

Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Supply voltage	V_{CC}	-0.5 to +7.0	V
Input diode current	I_{IK}	± 30	mA
Input voltage	V_{IN}	-0.5 to +7.5	V
Output voltage	V_{OUT}	-0.5 to +7.5	V
Off state output voltage	$V_{OUT(off)}$	-0.5 to +5.5	V
Storage temperature	Tstg	-65 to +150	°C

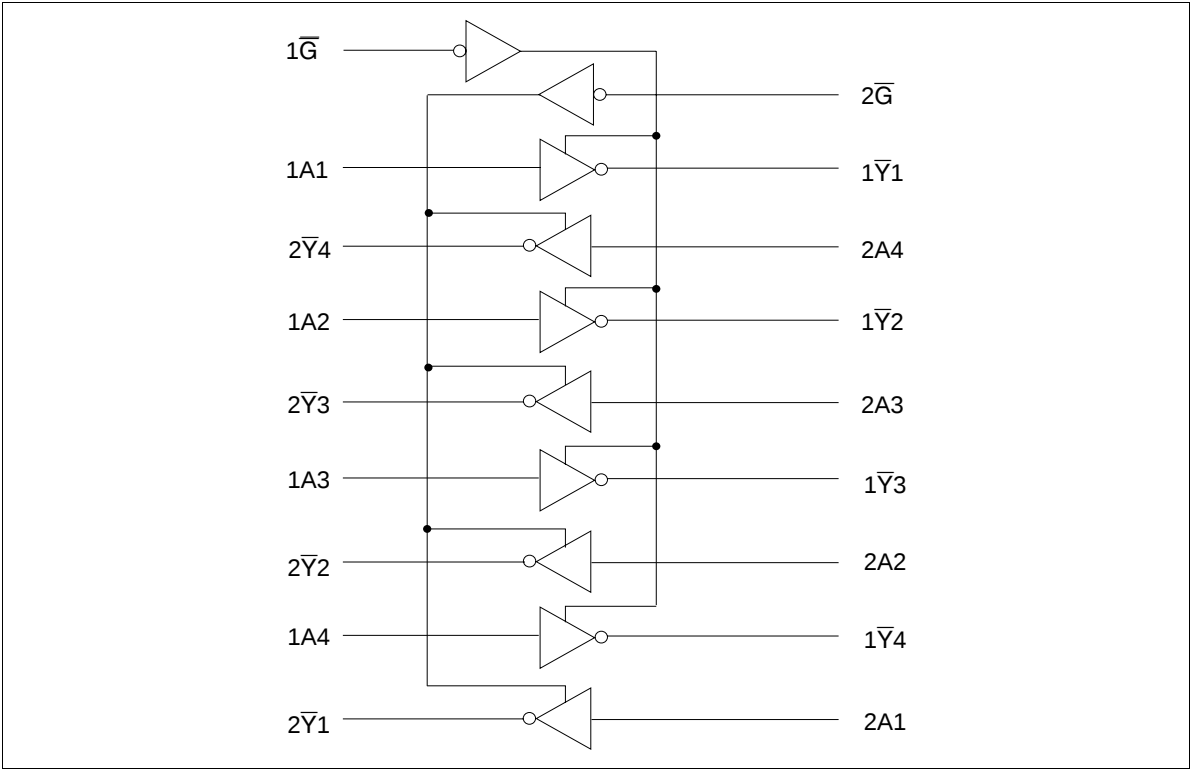
Note: 1. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{CC}	4.5	5.0	5.5	V
Input voltage	V_{IN}	0	—	V_{CC}	V
Output voltage	V_{OUT}	0	—	V_{CC}	V
Operating temperature	T_{opr}	−40	—	85	°C
Input rise/fall time*1	t_r, t_f	0	—	8	ns/V

Note: 1. This item guarantees maximum limit when one input switches.
Waveform: Refer to test circuit of switching characteristics.

Logic Diagram



Electrical Characteristics (Ta = -40°C to +85°C)

Item	Symbol	V _{cc} (V)	Min	Max	Unit	Test Conditions
Input voltage	V _{IH}		2.0	—	V	
	V _{IL}		—	0.8	V	
Output voltage	V _{OH}	4.5	2.4	—	V	I _{OH} = -3 mA
		4.5	2.0	—	V	I _{OH} = -15 mA
	V _{OL}	4.5	—	0.5	V	I _{OL} = 48 mA
		4.5	—	0.55	V	I _{OL} = 64 mA
Input diode voltage	V _{IK}	4.5	—	-1.2	V	I _{IN} = -18 mA
Input current	I _I	5.5	—	-250	μA	V _{IN} = 0 V
		5.5	—	1.0	μA	V _{IN} = 5.5 V
		5.5	—	100	μA	V _{IN} = 7.0 V
Short circuit output current*1	I _{OS}	5.5	-100	-225	mA	V _{IN} = 0 or 5.5 V
Off state output current	I _{OZH}	5.5	—	50	μA	V _O = 2.7 V
	I _{OZL}	5.5	—	-50	μA	V _O = 0.5 V
Supply current	I _{CCL}	5.5	—	27.5	mA	V _{IN} = 0 or 5.5 V All outputs is "L"
	I _{CCH}	5.5	—	2.5	mA	V _{IN} = 0 or 5.5 V All outputs is "H"
	I _{CCZ}	5.5	—	2.5	mA	V _{IN} = 0 or 5.5 V All outputs is "Z"
	I _{CCT} *2	5.5	—	1.5	mA	V _{IN} = 3.4 or 0.5 V

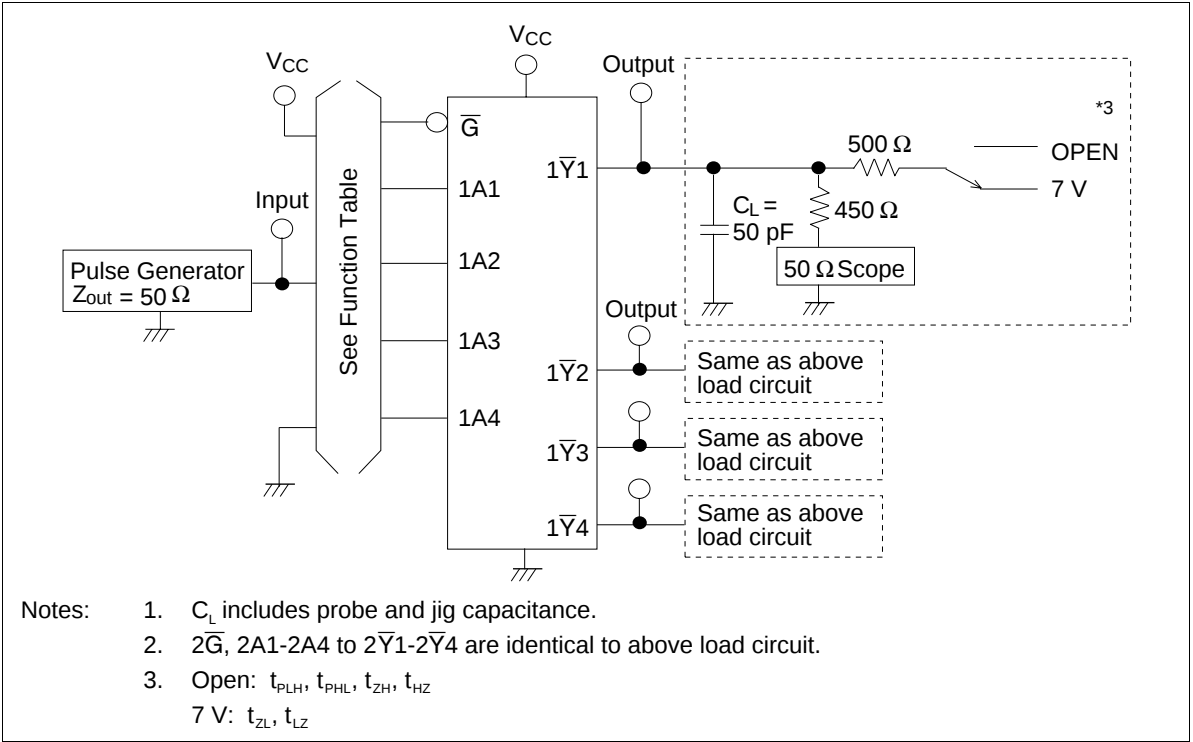
Notes: 1. Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

2. When input by the TTL level, it shows I_{cc} increase at per one input pin.

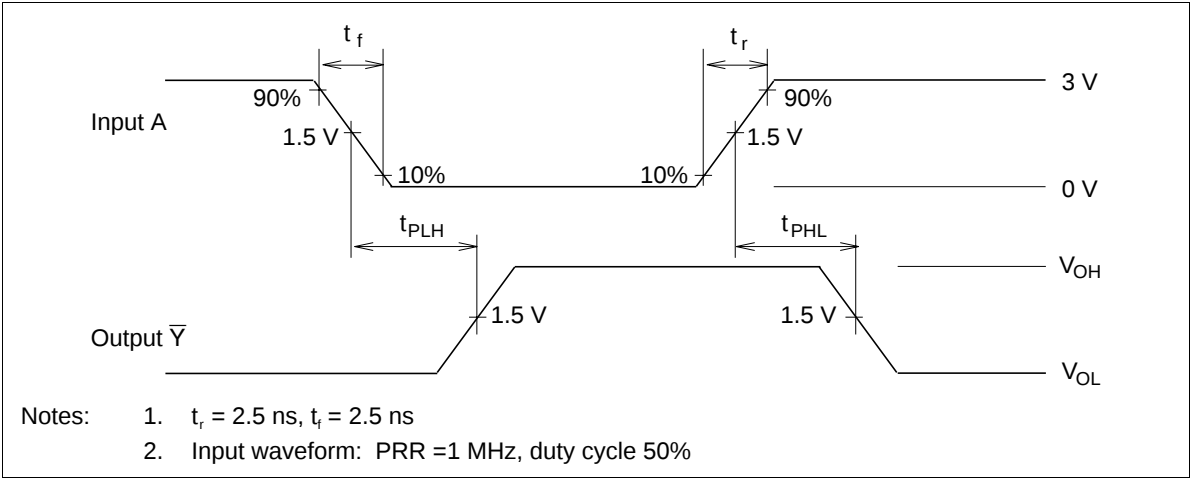
Switching Test Method ($C_L = 50\text{ pF}$)

Item	Symbol	$T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{ V}$		$T_a = -40\text{ to }85^\circ\text{C}$ $V_{CC} = 5.0\text{ V} \pm 10\%$		Unit	Test Conditions
		Min	Max	Min	Max		
Propagation delay time	t_{PLH}	3.0	6.0	3.0	7.0	ns	See under figure
	t_{PHL}	3.0	6.0	3.0	7.0		
Output enable time	t_{ZH}	3.0	8.0	3.0	10.0	ns	
	t_{ZL}	3.0	8.0	3.0	10.0		
Output disable time	t_{HZ}	3.0	7.0	3.0	9.0	ns	
	t_{LZ}	3.0	7.0	3.0	9.0		
Input capacitance	C_{IN}	3.0(Typ)		—		pF	$V_{IN} = V_{CC}\text{ or GND}$
Output capacitance	C_O	15.0(Typ)		—		pF	$V_O = V_{CC}\text{ or GND}$

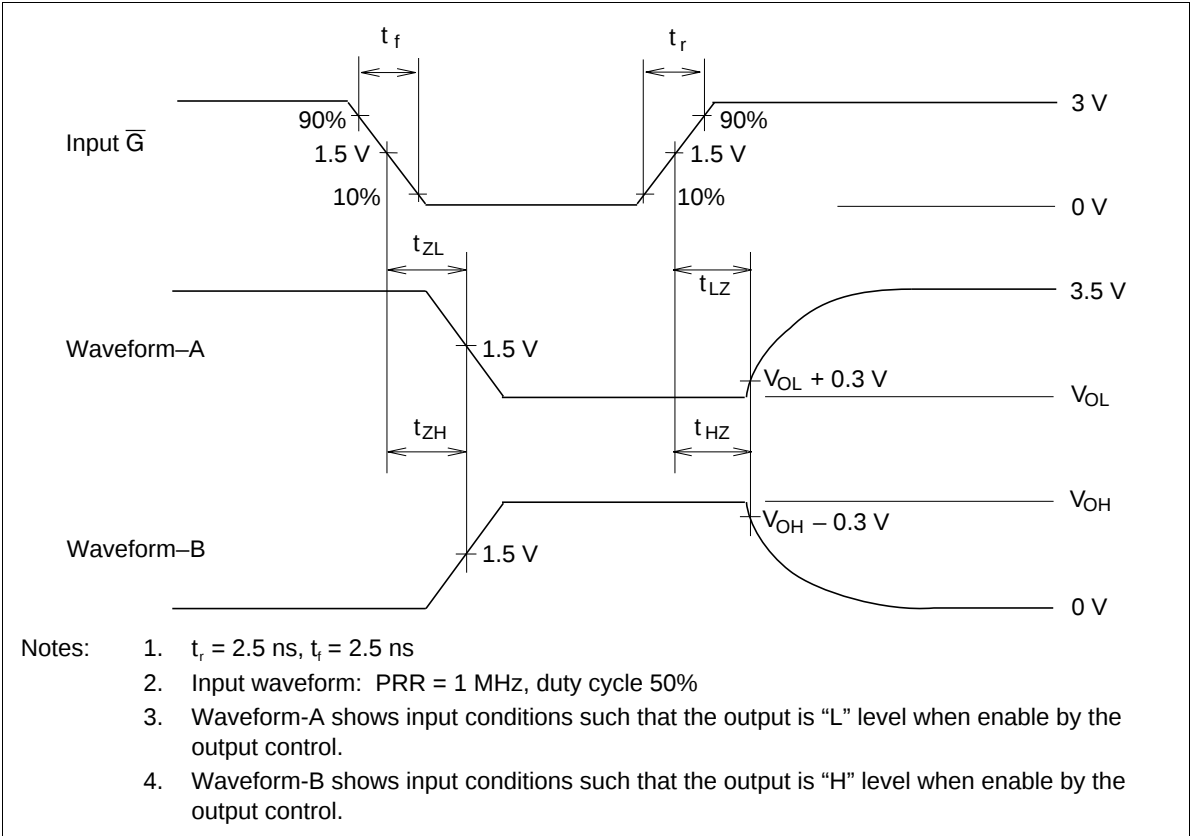
Test Circuit



Waveforms-1

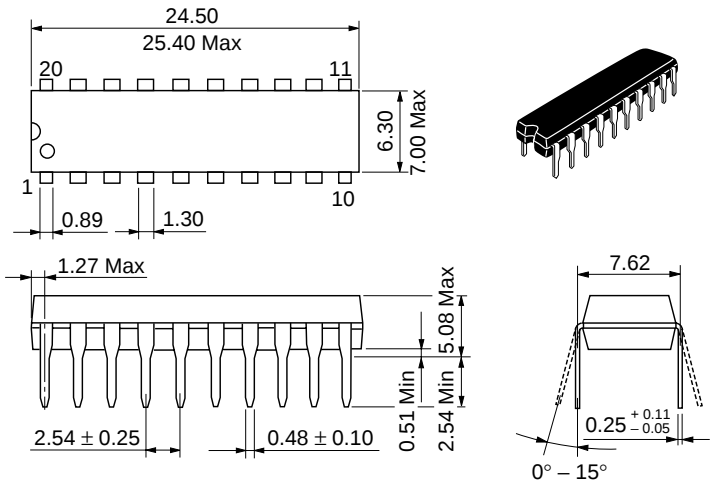


Waveforms-2



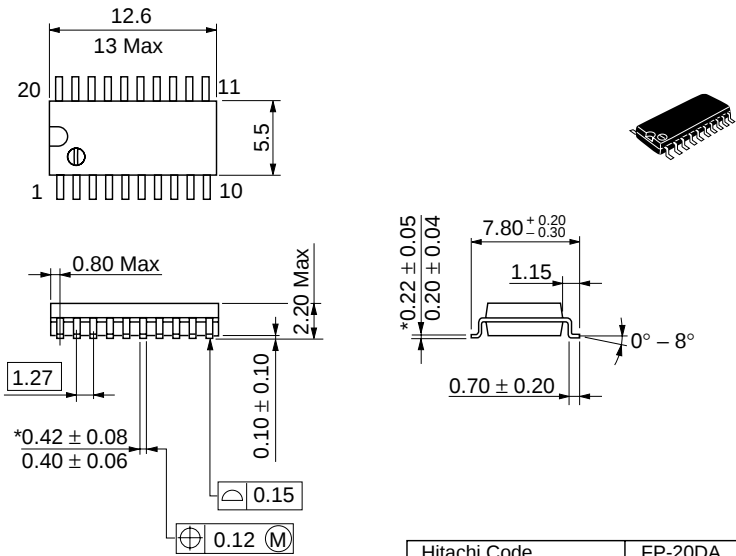
Package Dimensions

Unit: mm



Hitachi Code	DP-20N
JEDEC	—
EIAJ	Conforms
Mass (reference value)	1.26 g

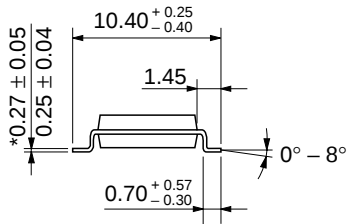
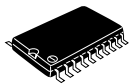
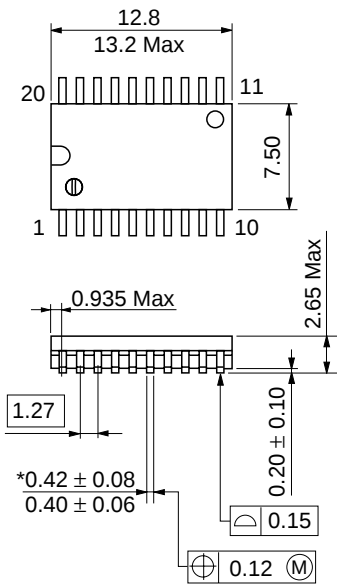
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-20DA
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.31 g

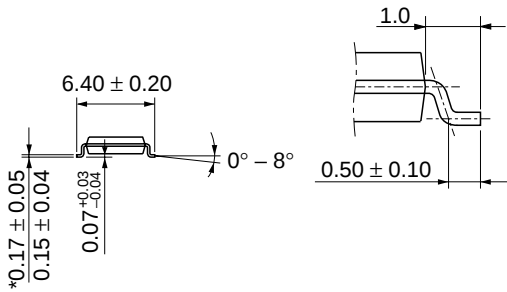
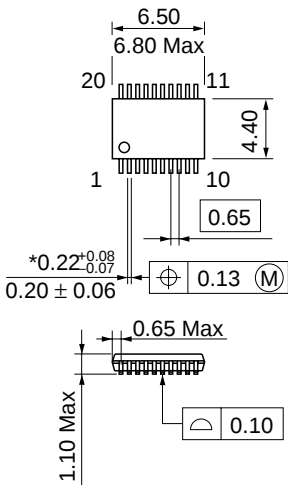
Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-20DB
JEDEC	Conforms
EIAJ	—
Mass (reference value)	0.52 g

Unit: mm



*Dimension including the plating thickness
Base material dimension

Hitachi Code	TTP-20DA
JEDEC	—
EIAJ	—
Mass (reference value)	0.07 g

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HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

URL	NorthAmerica	:	http://semiconductor.hitachi.com/
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For further information write to:

Hitachi Semiconductor
(America) Inc.
179 East Tasman Drive,
San Jose, CA 95134
Tel: <1> (408) 433-1990
Fax: <1> (408) 433-0223

Hitachi Europe GmbH
Electronic Components Group
Dornacher Straße 3
D-85622 Feldkirchen, Munich
Germany
Tel: <49> (89) 9 9180-0
Fax: <49> (89) 9 29 30 00

Hitachi Europe Ltd.
Electronic Components Group.
Whitebrook Park
Lower Cookham Road
Maidenhead
Berkshire SL6 8YA, United Kingdom
Tel: <44> (1628) 585000
Fax: <44> (1628) 585160

Hitachi Asia Ltd.
Hitachi Tower
16 Collyer Quay #20-00,
Singapore 049318
Tel: <65>-538-6533/538-8577
Fax: <65>-538-6933/538-3877
URL: <http://www.hitachi.com.sg>

Hitachi Asia Ltd.
(Taipei Branch Office)
4/F, No. 167, Tun Hwa North Road,
Hung-Kuo Building,
Taipei (105), Taiwan
Tel: <886>-(2)-2718-3666
Fax: <886>-(2)-2718-8180
Telex: 23222 HAS-TP
URL: <http://www.hitachi.com.tw>

Hitachi Asia (Hong Kong) Ltd.
Group III (Electronic Components)
7/F., North Tower,
World Finance Centre,
Harbour City, Canton Road
Tsim Sha Tsui, Kowloon,
Hong Kong
Tel: <852>-(2)-735-9218
Fax: <852>-(2)-730-0281
URL: <http://www.hitachi.com.hk>

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